

# YA869C04R

**FUJI Diode** 

# **Schottky Barrier Diode**

### Maximum Rating and Characteristics

#### • Maximum ratings (at Ta=25°C unless otherwise specified.)

Item	Symbols	Conditions	Ratings	Units
Repetitive peak reverse voltage	Vrrm	-	45	V
Average output current	lo	50Hz Square wave duty =1/2 Tc = 120°C	40*	A
Non-repetitive forward surge current**	IFSM	Sine wave, 10ms 1shot	190	A
Operating junction temperature	Tj	-	150	°C
Storage temperature	Tstg	-	-40 to +150	°C

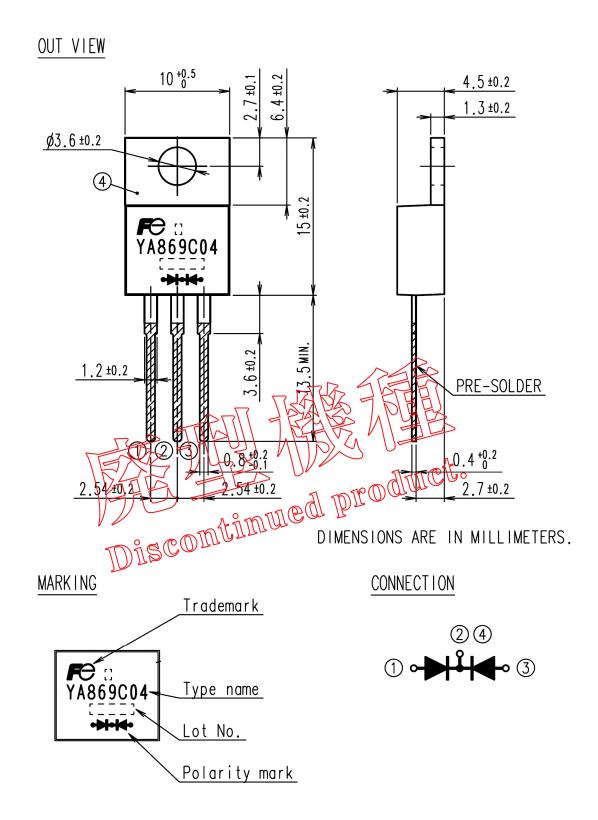
Note\* Out put current of center tap full wave connection.

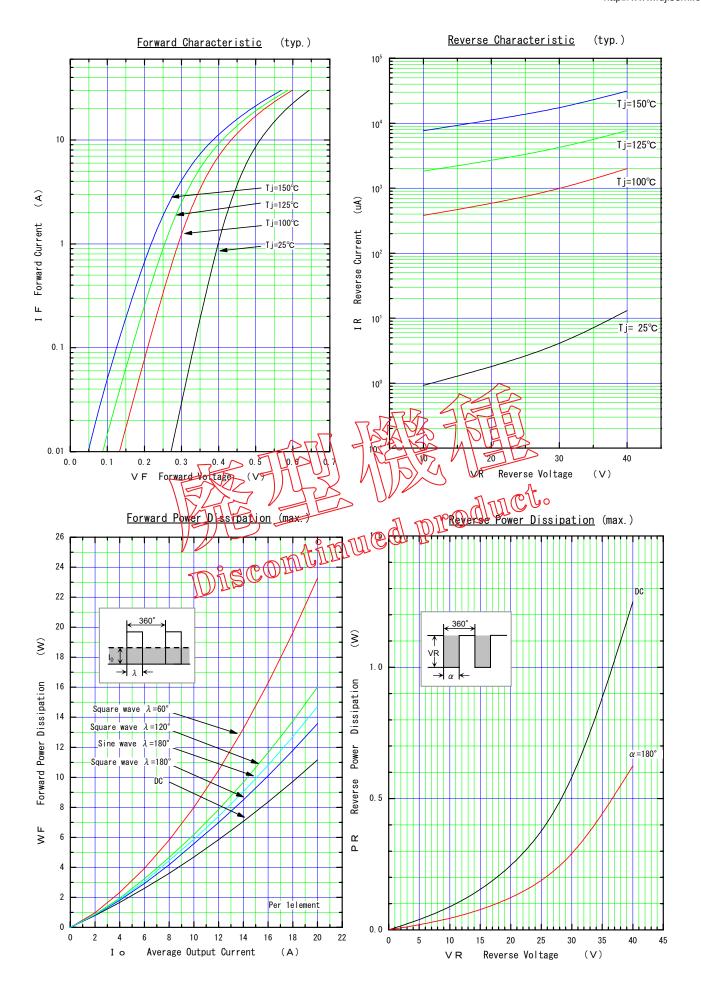
Note\*\* Rating per element

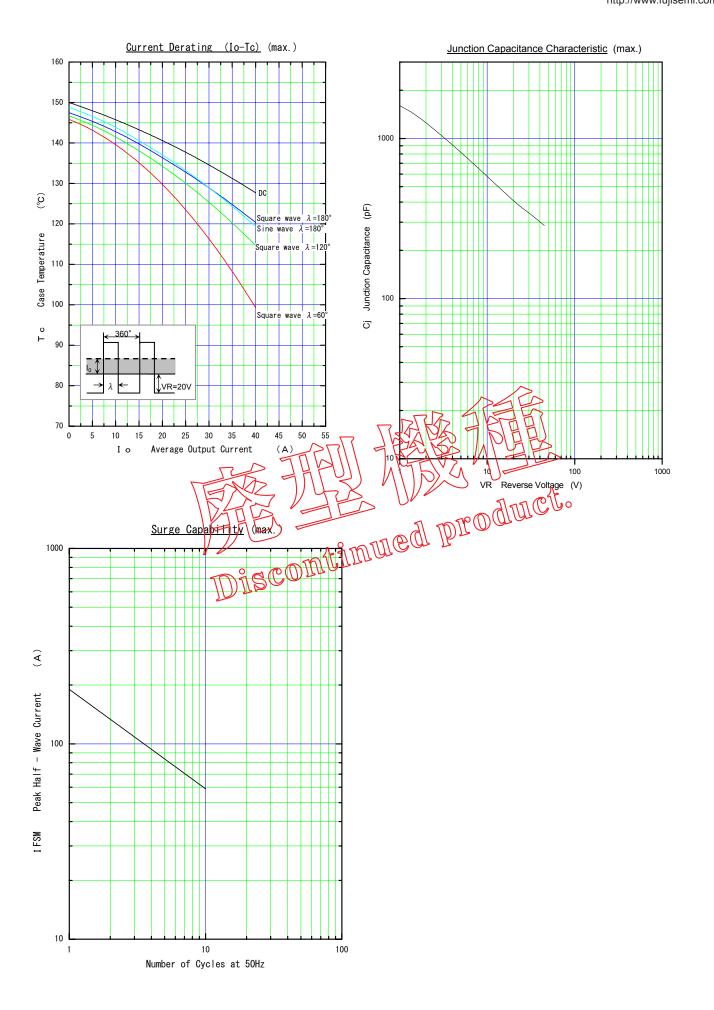
#### • Electrical characteristics (at Ta=25°C unless otherwise specified.)

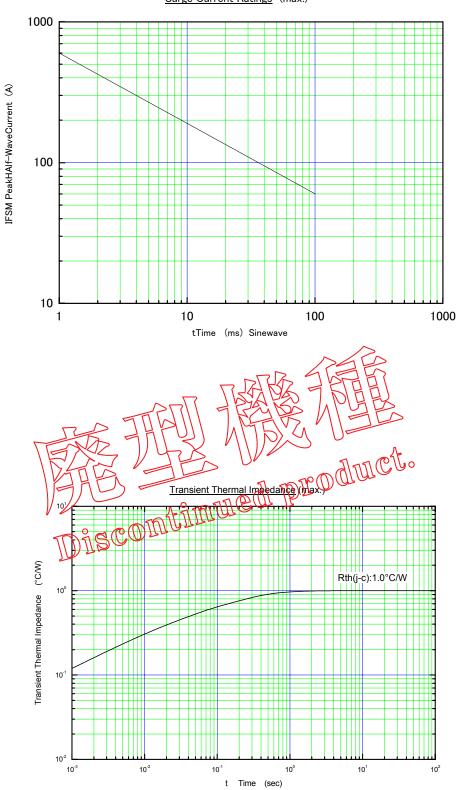
Item		Symbols	Conditions	Maximum	Units			
Forward voltage***		VF	IF =20 A	0.61	V			
Reverse current***		IR		0.20	mA			
Thermal resistance		Rth(j-c)	Junction to case	1.0	°C/W			
Mechanical characteristics								
Item	MAR -		Condition	Maximum	Units			
Mounting torque	MB	IN OF	commended torque	0.3 to 0.5	N•m			
Approximate mass	nft i	IN ULS	-	2.0	g			
	Discome							

## Outline Drawings [mm]









Surge Current Ratings (max.)

